SEMICONDUCTOR MACROATOMS

Basic Physics and Quantum-device Applications

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Contents

Preface v

1. Fundamentals of Zero-Dimensional Nanostructures 1
   1.1 Introduction .................................................... 1
   1.2 Structural Information on Quantum Dots ....................... 3
   1.3 Single-Particle Electronic States in Quantum Dots ............. 7
      1.3.1 Eigenstates in the absence of external perturbations 7
      1.3.2 Effect of "external" fields ............................... 12
         1.3.2.1 Electric field effects .............................. 12
         1.3.2.2 Magnetic field effects .............................. 14
      1.3.3 Dot-dot interaction in stacked dots; quantum dot molecules 16
   1.4 Optical Properties ............................................ 17
      1.4.1 The idealized quantum dot: a two-level atom.
         Populations and coherence. ................................ 17
      1.4.2 Optical properties of dot ensembles. Broadening and
         selection rules ........................................... 19
      1.4.3 Single dot spectroscopy: the failure of the simple
         ideas ....................................................... 21
   1.5 Phonons and Carrier Coupling to the Phonons in Quantum
      Dots ............................................................. 26
   1.6 Carrier-Carrier Interaction in Quantum Dots ................... 32
      1.6.1 Electron-hole interaction in quantum dots ............... 33
      1.6.2 Excitonic complexes and optical properties of highly
         excited quantum dots: new phenomena and a new approach 36
1.6.3 Auger scattering in quantum dots ............. 39

2. Growth and Characterization of Self-Assembled Semiconductor Macroatoms 51
   2.1 Introduction ........................................ 51
      2.1.1 Semiconductor quantum dots ................. 53
   2.2 Fabrication and Structural Analysis of InGaAs/GaAs Quantum Dots ............. 54
   2.3 Nanotechnological Strategies for the Fabrication of Single-Dot Structures .......... 61
   2.4 Modeling of the Carrier Wavefunctions .......... 64
   2.5 Photoluminescence Experiments ................... 73
   2.6 Single-Dot Spectroscopy ......................... 78
      2.6.1 Wavefunction spectroscopy ................. 78
      2.6.2 Optical spectroscopy ....................... 85
   2.7 Conclusions ......................................... 92

3. Ultrafast Coherent Spectroscopy of Single Semiconductor Quantum Dots 101
   3.1 Introduction ....................................... 101
   3.2 Semiconductor Quantum Dots ..................... 104
      3.2.1 Interface quantum dots .................... 104
      3.2.2 Self-assembled quantum dots .................. 107
   3.3 Experimental Techniques ......................... 114
      3.3.1 Coherent spectroscopy on interface quantum dots .......... 115
      3.3.2 Coherent spectroscopy on self-assembled quantum dots ............. 119
   3.4 Results ............................................. 123
      3.4.1 Coherent control in single interface quantum dots .......... 123
         3.4.1.1 Ultrafast optical nonlinearities of single interface quantum dots .......... 123
         3.4.1.2 Optical Stark effect and Rabi oscillations in a quantum dot: ultrafast control of single exciton polarizations .......... 128
      3.4.2 Coherent control in single self-assembled quantum dots ............... 138
   3.5 Outlook ............................................. 143

4. Few-Particle Effects in Semiconductor Macroatoms/Molecules 151
6.3 Analytical Results for Excitations with Ultrafast Pulses
   6.3.1 Linear single-dot spectra
   6.3.2 The initial decay of four-wave-mixing signals
   6.3.3 Impact of pure dephasing on electronic and phononic occupations

6.4 Influences of Temporal and Spectral Properties of the Laser Excitation on the Decoherence
   6.4.1 Phonon-induced damping of Rabi oscillations in quantum dots
   6.4.2 Optimal gating strategy: a trade-off between different types of decoherence

6.5 Conclusions

7. All-Optical Schemes for Quantum Information Processing with Semiconductor Macroatoms
   7.1 Introduction
   7.2 All-Optical Quantum Information/Computation with Semiconductor Macroatoms
      7.2.1 Single-dot encoding schemes
      7.2.2 Coupled-dot encoding schemes
         7.2.2.1 GaAs-based quantum hardware
         7.2.2.2 GaN-based quantum hardware
      7.2.3 Combination of charge and spin degrees of freedom
         7.2.3.1 Artificial molecules as qubits and Raman adiabatic passages for the optical gating
   7.3 Summary and Conclusions

   8.1 Introduction
   8.2 Field-Induced Exciton-Exciton Coupling in Semiconductor Quantum Dots with no Intrinsic Bias
   8.3 Modeling Few Particle Interactions in Quantum Dots with Intrinsic Bias
      8.3.1 Engineering electronic structure and optical spectrum in coupled GaN quantum dots
      8.3.2 Semi-analytical model
         8.3.2.1 Single exciton system
8.3.2.2 Biexciton system ........................................ 299
8.4 Semiconductor Double Quantum Dot as Storage Qubit ... 303
  8.4.1 Definition .................................................. 303
  8.4.2 Measurement using a STIRAP process ................. 305
    8.4.2.1 Failure of the adiabatic condition .......... 308
    8.4.2.2 Failure of the energy conservation
            requirement ........................................ 310
8.5 All-Optical Read-Out Device ............................ 311

Index .................................................................. 317